Characteristics ACST310-8B

1 Characteristics

Table 2. Absolute ratings (limiting values)

Symbol	Parameter Test		onditions	Value	Unit
I _{T(RMS)}	On-state RMS current (full sine wave)		T _c = 112 °C	3	Α
	Non repetitive surge peak on-state current	f = 50 Hz	t _p = 20 ms	20	Α
I _{TSM}	(T _j initial = 25 °C)	f = 60 Hz	t _p = 16.7 ms	21	7 ^
l ² t	I ² t value for fusing (T _j initial = 25 °C)		t _p = 10 ms	2.6	A²s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r = 100 \text{ ns}$ $f = 120 \text{ Hz}$		T _j = 125 °C	50	A/µs
V _{PP} ⁽¹⁾	Non repetitive line peak mains voltage	T _j = 25 °C	2	kV	
P _{G(AV)}	Average gate power dissipation		T _j = 125 °C	0.1	W
P_{GM}	Peak gate power	t _p = 20 μs	T _j = 125 °C	10	W
I _{GM}	Peak gate current	t _p = 20 μs	T _j = 125°C	1.6	Α
T _{stg}	Storage junction temperature range			-40 to +150	°C
Tj	Operating junction temperature range			-40 to +125	°C
T _L	Maximum lead temperature for soldering during 10 s			260	°C

^{1.} according to test described by IEC 61000-4-5 standard (see Figure 18).

Table 3. Electrical characteristics

Symbol	Test conditions	Quadrant	Tj		Value	Unit
I _{GT} ⁽¹⁾	V _{OUT} = 12 V, R _I = 33 Ω	1 - 11 - 111	25 °C	Max.	10	mA
V _{GT}	$V_{OUT} = 12 \text{ V}, R_L = 33 \Omega$	1 - 11 - 111	25 C	Max.	1.1	V
V_{GD}	$V_{OUT} = V_{DRM}, R_L = 3.3 \text{ k}\Omega$	1 - 11 - 111	125 °C	Min.	0.2	V
I _H ⁽²⁾	I _{OUT} = 100 mA	25 °C	Max.	20	mA	
	I _G = 1.2 x I _{GT}	I - III	25 °C	Max.	25	mA
ΙL		II			35	
dV/dt ⁽²⁾	V _{OUT} = 67% V _{DRM} , gate open		125 °C	Min.	1000	V/µs
(dl/dt)c ⁽²⁾	(dV/dt)c = 0.1V/μs		125 °C	Min.	5	A/ms
(dl/dt)c ⁽²⁾	(dV/dt)c = 10 V/μs		125 °C	Min.	1	A/ms
V _{CL} ⁽²⁾	I _{CL} = 0.1 mA, tp = 1 ms	25 °C	Min.	850	V	

^{1.} Minimum $I_{\mbox{\scriptsize GT}}$ is guaranteed at 5% of $I_{\mbox{\scriptsize GT}}$ max.

^{2.} For both polarities of OUT pin referenced to COM pin

ACST310-8B Characteristics

Table 4. Static characteristics

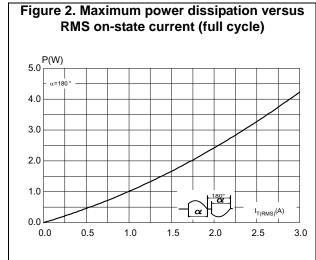
Symbol	Test conditions			Value		
V _{TM} ⁽¹⁾	$I_{TM} = 4.2 \text{ A}, t_p = 380 \mu\text{s}$	T _j = 25 °C	Max.	1.8	V	
V _{TO} ⁽¹⁾	Threshold voltage	T _j = 125 °C	Max.	0.9	V	
R _D ⁽¹⁾	Dynamic resistance	T _j = 125 °C	Max.	200	mΩ	
I _{DRM} I _{RRM}	V -V /V	T _j = 25 °C	- Max.	10	μΑ	
	$V_{OUT} = V_{DRM} / V_{RRM}$	T _j = 125 °C		500		

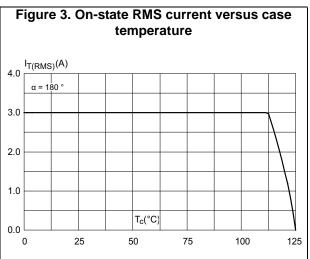
^{1.} For both polarities of OUT pin referenced to COM pin

Table 5. Thermal resistances

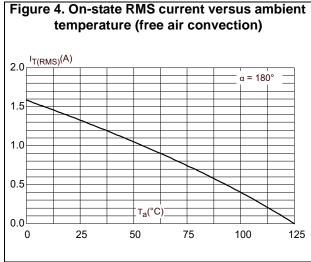
Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case (AC)	3	°C/W
R _{th(j-a)}	Junction to ambient $S_{Cu}^{(1)} = 0.5 \text{ cm}^2$	70	°C/W

^{1.} S_{cu} = copper surface under tab





Characteristics ACST310-8B



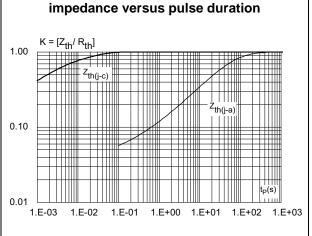


Figure 5. Relative variation of thermal

Figure 6. Non repetitive surge peak on-state current for a sinusoidal pulse with width: tp < 10ms

1.E+03

1.E+01

1.E+00

1.E+00

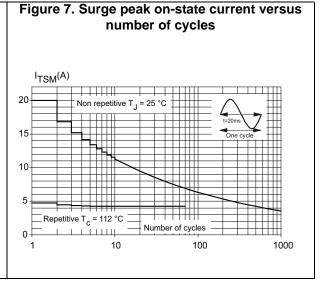
1.E+01

0.01

0.10

1.00

1.00



ACST310-8B Characteristics

Figure 8. Relative variation of holding current and latching current versus junction temperature (typical values)

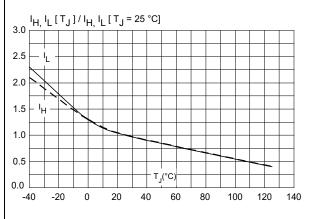


Figure 9. Relative variation of gate trigger current and gate trigger voltage versus junction temperature (typical values)

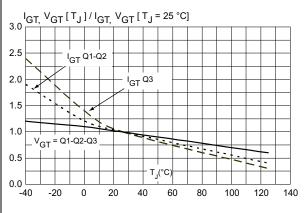


Figure 10. On-state characteristics (maximum values)

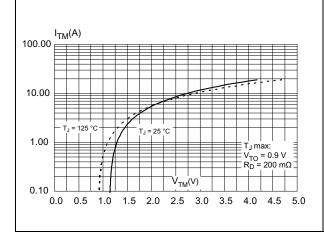
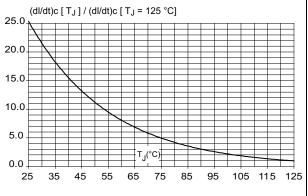


Figure 11. Relative variation of critical rate of decrease of main current versus junction temperature (typical values)



Characteristics ACST310-8B

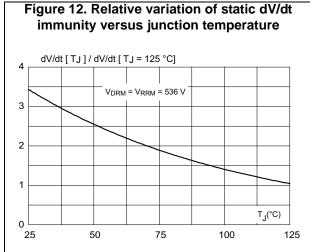


Figure 13. Relative variation of leakage current versus junction temperature (typical values)

1.E+00 | DRM/IRRM [TJ] / IDRM/IRRM [TJ = 125 °C]

1.E-01 | VDRM = VRRM = 800 V

1.E-02 | TJ(°C)

1.E-03 | 25 | 50 | 75 | 100 | 125

Figure 14. Relative variation of critical rate of decrease of main current versus reapplied (dV/dt) (typical value)

6.0 (dl/dt)c [(dV/dt)c] / specified (dl/dt)c

(dl/dt)c [(dV/dt)c] / specified (dl/dt)c

5.0

4.0

3.0

2.0

1.0

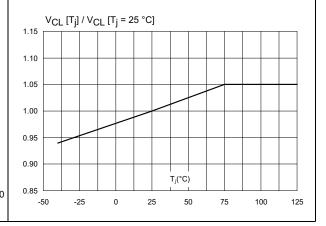
(dV/dt)c(V/µs)

0.1

1.0

100.0

Figure 15. Relative variation of the maximal clamping voltage versus junction temperature (min. value)



577

6/14 DocID030200 Rev 1

2 Application information

2.1 Typical application description

The ACST310-8B device has been designed to switch on and off, or by phase angle control, highly inductive or resistive loads such as pump, valve, fan, or bulb lamps. Thanks to its high sensitivity (I_{GT} max = 10 mA), this device can be driven directly by logic level circuits through a resistor as shown on the typical application diagram (*Figure 16*).

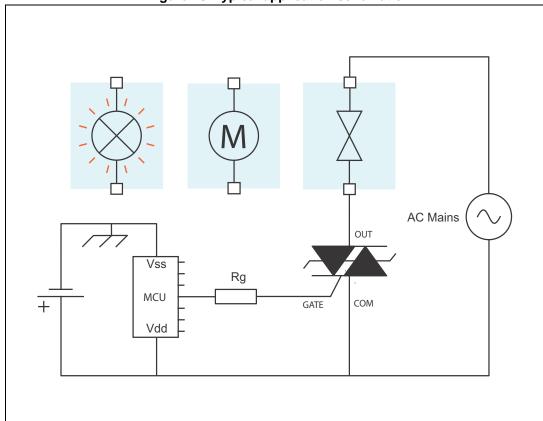


Figure 16. Typical application schematic

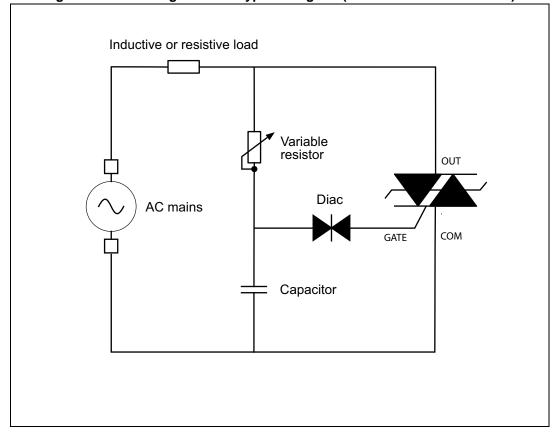


Figure 17. Phase angle control typical diagram (inductive or resistive load)

577

2.2 AC line transient voltage ruggedness

In comparison with standard Triacs, which are not robust against surge voltage, the ACST310-8B is self-protected against over-voltage, specified by the parameter V_{CL} . In addition, the ACST310-8B is a sensitive device (I_{GT} max. 10 mA), but provides a high noise immunity level against fast transients. The ACST310-8B switch can safely withstand AC line transient voltages either by clamping the low energy spikes, such as inductive spikes at switch off, or by switching to the on state (for less than 10 ms) to dissipate higher energy shocks through the load. This safety feature works even with high turn-on current ramp up.

The test circuit of *Figure 18* represents the ACST310-8B application, and is used to stress the ACST310-8B switch according to the IEC 61000-4-5 standard conditions. With the additional effect of the load which is limiting the current, the ACST310-8B switch withstands the voltage spikes up to 2 kV on top of the peak line voltage. The protection is based on an overvoltage crowbar technology. The ACST310-8B folds back safely to the on state as shown in *Figure 19*. The ACST310-8B recovers its blocking voltage capability after the surge and the next zero current crossing. Such a non-repetitive test can be done at least 10 times on each AC line voltage polarity.

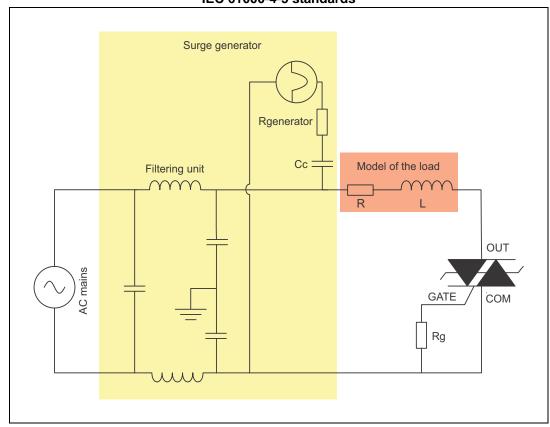


Figure 18. Overvoltage ruggedness test circuit for resistive and inductive loads for IEC 61000-4-5 standards

1. R = 30 Ω , L = 10 μ H, V_{pp} = 2 kV (Surge Generator), Rg = 220 Ω , AC mains = 230 V_{RMS} 50 Hz

5/

DocID030200 Rev 1

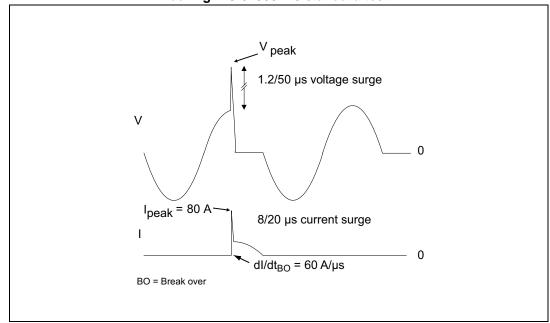


Figure 19. Typical voltage and current waveforms across the ACST310-8B during IEC 61000-4-5 standard test

2.3 Electrical noise immunity

The ACST310-8B is a sensitive device (I_{GT} max. 10 mA) and can be controlled directly through a simple resistor by a logic level circuit, and still provides a high electrical noise immunity. The intrinsic immunity of the ACST310-8B is shown by the specified dV/dt equal to 1000 V/ μ s at 125 °C. This immunity level is 5 to 10 times higher than the immunity provided by an equivalent standard technology Triac with the same sensitivity. In other words, the ACST310-8B with I_{GT} = 10 mA has immunity comparable only for higher gate current device (I_{GT} higher than 35 mA).

577

10/14 DocID030200 Rev 1

Package information 3

- Epoxy meets UL94-V0
- Lead-free package
- Halogen free molding compound

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

DPAK package information 3.1

Figure 20. DPAK package outline

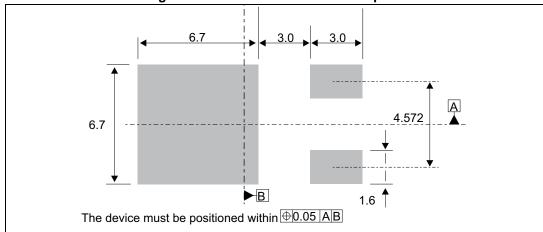
Package information ACST310-8B

Table 6. DPAK package mechanical data

	Dimensions						
Ref.	Millimeters			Inches ⁽¹⁾			
	Тур.	Min.	Max.	Тур.	Min.	Max.	
А		2.18	2.40		0.0858	0.0945	
A1		0.90	1.10		0.0354	0.0433	
A2		0.03	0.23		0.0012	0.0091	
b		0.64	0.90		0.0252	0.0354	
b4		4.95	5.46		0.1949	0.2150	
С		0.46	0.61		0.0181	0.0240	
c2		0.46	0.60		0.0181	0.0236	
D		5.97	6.22		0.2350	0.2449	
D1		4.95	5.60		0.1949	0.2205	
E		6.35	6.73		0.2500	0.2650	
E1		4.32	5.50		0.1701	0.2165	
е	2.286			0.09			
e1		4.40	4.70		0.1732	0.1850	
Н		9.35	10.40		0.3681	0.4094	
L		1.00	1.78		0.0394	0.0701	
L2			1.27			0.0500	
L4		0.60	1.02		0.0236	0.0402	
V2		-8 °	+8 °		-8 °	+8 °	

^{1.} Inches only for reference

Figure 21. DPAK recommended footprint



577

ACST310-8B Ordering information

4 Ordering information

Figure 22. Ordering information scheme

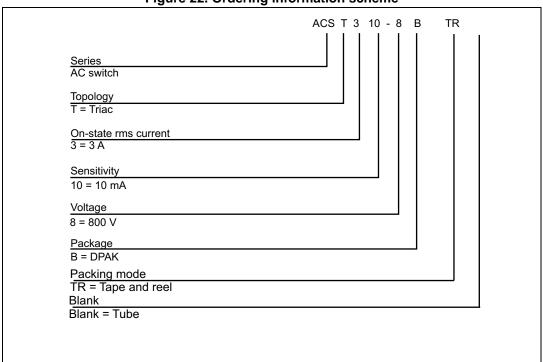


Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty.	Packing mode
ACST310-8B	ACST 3108	DPAK	0.32 g per pc.	75	Tube
ACST310-8BTR	A031 3100	DIAK		2500	Tape and reel

5 Revision history

Table 8. Document revision history

Date	Revision	Changes
24-Feb-2017	1	Initial release.

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57

14/14 DocID030200 Rev 1